NSN 5961-01-032-8867

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-032-8867 **Inclosure Material:** Plastic **Overall Length:** Between 0.330 inches and 0.385 inches **Terminal Length:** 0.240 inches **Overall Height:** Between 0.049 inches and 0.080 inches **Overall Width:** Between 0.235 inches and 0.270 inches **Component Name And Quantity:** 10 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 30.0 reverse voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 100.00 milliamperes forward current, average all semiconductor device diode **Power Rating Per Characteristic:** 417.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Dual five input common anode diode array **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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